

FCH072N60F\_F085

## N-Channel SuperFET II FRFET MOSFET

## 600 V, 52 A, 72 m $\Omega$

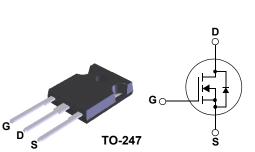
### Features

- Typical  $R_{DS(on)}$  = 62 m $\Omega$  at  $V_{GS}$  = 10 V,  $I_D$  = 26 A
- Typical  $Q_{g(tot)}$  = 160 nC at  $V_{GS}$  = 10V,  $I_D$  = 26 A
- UIS Capability
- Qualified to AEC Q101
- RoHS Compliant

## Description

SuperFET® II MOSFET is Fairchild Semiconductor's brand-new high voltage super-junction (SJ) MOSFET family that is utilizing charge balance technology for outstanding low on-resistance and lower gate charge performance. This technology is tailored to minimize conduction loss, provide superior switching performance, dv/dt rate and higher avalanche energy. Consequently SuperFETII is very well suited for the Soft switching and Hard Switching topologies like High Voltage Full Bridge and Half Bridge DC-DC, Interleaved Boost PFC, Boost PFC for HEV-EV automotive.

SuperFET II FRFET® MOSFET's optimized body diode reverse recovery performance can remove additional component and improve system reliability.



For current package drawing, please refer to the Fairchild website at https://www.fairchildsemi.com/package-drawings/TO/ TO247A03.pdf

## Application

- Automotive On Board Charger
- Automotive DC/DC converter for HEV



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Symbol	Parameter	Ratings	Units	
V <sub>DSS</sub>	Drain to Source Voltage		600	V
V <sub>GS</sub>	Gate to Source Voltage	±20	V	
I <sub>D</sub>		T <sub>C</sub> = 25°C	52	А
	Drain Current - Continuous (V <sub>GS</sub> =10) (Note 1)	$T_{C}^{-} = 100^{\circ}C$	33	А
	Pulsed Drain Current	See Fig 4	А	
E <sub>AS</sub>	Single Pulse Avalanche Rating (Note 2)		1128	mJ
dv/dt	MOSFET dv/dt	100	V/no	
	Peak Diode Recovery dv/dt	(Note 3)	50	V/ns
<b>D</b>	Power Dissipation	481	W	
P <sub>D</sub>	Derate Above 25°C	3.85	W/ºC	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature	-55 to + 150	°C	
$R_{\theta JC}$	Maximum Thermal Resistance Junction to Case	0.26	°C/W	
$R_{\thetaJA}$	Maximum Thermal Resistance Junction to Ambie	40	°C/W	

# **Maximum Ratings** $T_{C} = 25^{\circ}C$ unless otherwise noted

#### Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FCH072N60F	FCH072N60F_F085	TO-247	-	-	30

Notes:

1: Current is limited by bondwire configuration.

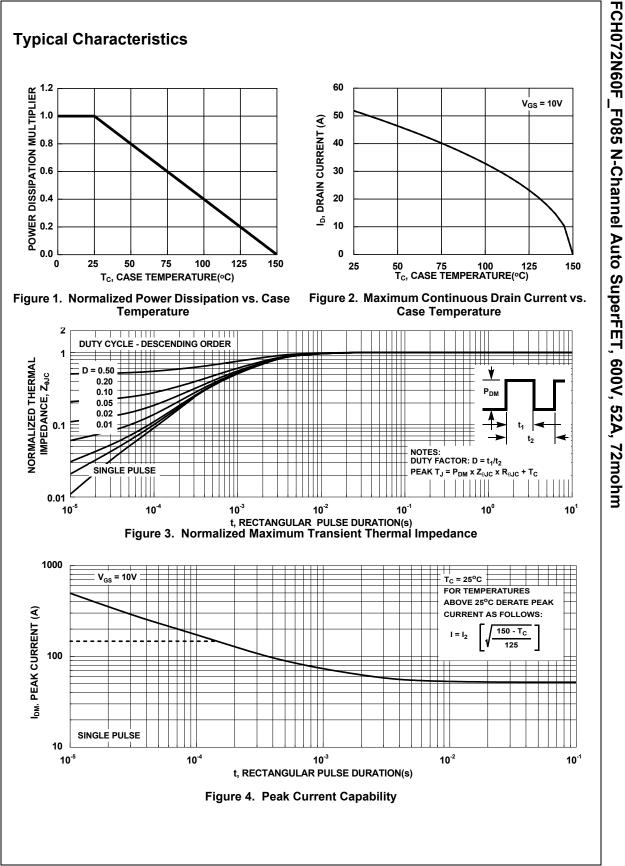
2: Starting  $T_J = 25^{\circ}$ C, L = 25mH,  $I_{AS} = 9.5$ A,  $V_{DD} = 100$ V during inductor charging and  $V_{DD} = 0$ V during time in avalanche.

3:  $I_{SD} \le 26A$ , di/dt  $\le 200$  A/us,  $V_{DD} \le 380V$ , starting  $T_J = 25^{\circ}C$ .

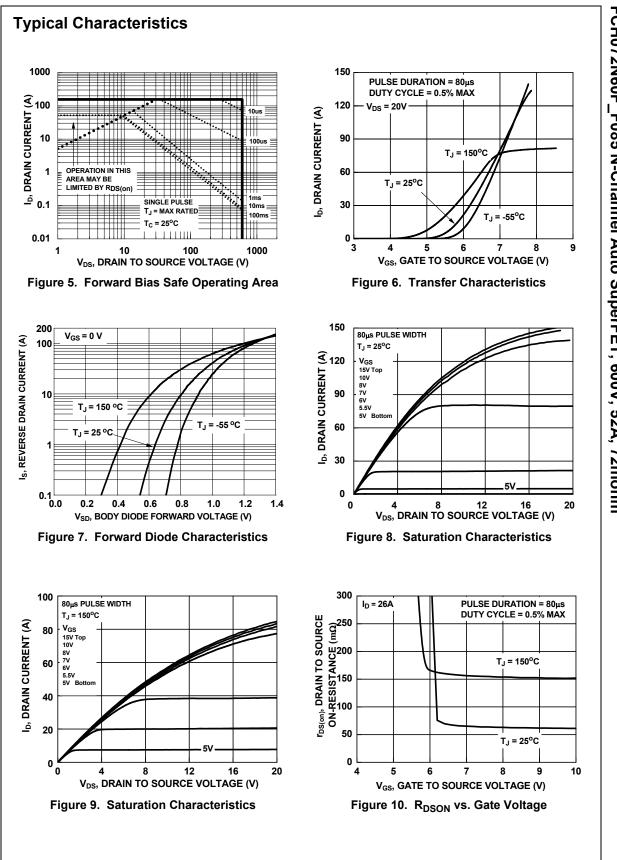
4: R<sub>0JA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>0JC</sub> is guaranteed by design, while R<sub>0JA</sub> is determined by the board design. The maximum rating presented here is based on mounting on a 1 in<sup>2</sup> pad of 2oz copper.

Symbol	Parameter	Test Conditions		Min	Тур	Max	Units		
Off Cha	racteristics								
B <sub>VDSS</sub>	Drain to Source Breakdown Voltage	I <sub>D</sub> = 250μA, V <sub>GS</sub> = 0V		Source Breakdown Voltage $I_D = 250 \mu A$ , $V_{CS} = 0$		600	-	-	V
		$V_{\rm DS}$ =600V, $T_{\rm J}$ = 25°C		-	-	10	μA		
IDSS	Drain to Source Leakage Current		$T_{\rm J} = 150^{\rm o} {\rm C}({\rm Note}\ 5)$	-	-	1	mA		
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA		
On Cha	racteristics								
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	V <sub>GS</sub> = V <sub>DS</sub> , I <sub>D</sub>	= 250µA	3.0	4.0	5.0	V		
· GS(III)		I <sub>D</sub> = 26A,		-	62	72	mΩ		
r <sub>DS(on)</sub>	Drain to Source On Resistance	$V_{GS} = 10V$	$T_{\rm J} = 150^{\circ} C(\text{Note 5})$	-	154	195	mΩ		
Dynami	c Characteristics			4	-1		1		
C <sub>iss</sub>	Input Capacitance			_	6330	-	pF		
C <sub>oss</sub>	Output Capacitance			-	199	-	pF		
C <sub>rss</sub>	Reverse Transfer Capacitance			-	1.25	-	pF		
R <sub>q</sub>	Gate Resistance	f = 1MHz		-	0.46	-	Ω		
Q <sub>g(ToT)</sub>	Total Gate Charge	$V_{DD} = 380V$ $I_{D} = 26A$ $V_{GS} = 10V$		-	160	210	nC		
Q <sub>g(th)</sub>	Threshold Gate Charge			-	11	16	nC		
Q <sub>gs</sub>	Gate to Source Gate Charge			-	34	-	nC		
Q <sub>gd</sub>	Gate to Drain "Miller" Charge			-	67	-	nC		
Switch	ing Characteristics								
t <sub>on</sub>	Turn-On Time			-	75	100	ns		
t <sub>d(on)</sub>	Turn-On Delay Time		_	-	44	-	ns		
t <sub>r</sub>	Rise Time	V <sub>DD</sub> = 380V,		-	31	-	ns		
t <sub>d(off)</sub>	Turn-Off Delay Time	V <sub>GS</sub> = 10V, R <sub>G</sub> = 4.7Ω		-	128	-	ns		
t <sub>f</sub>	Fall Time			-	22	-	ns		
t <sub>off</sub>	Turn-Off Time			-	150	200	ns		
Drain-S	ource Diode Characteristics								
V <sub>SD</sub>	Source to Drain Diode Voltage	I <sub>SD</sub> = 26A, V <sub>0</sub>	<sub>GS</sub> = 0V	-	-	1.2	V		
T <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 26A, dI <sub>S</sub>	<sub>D</sub> /dt = 100A/µs	-	185	-	ns		
Q <sub>rr</sub>	Reverse Recovery Charge	V <sub>DD</sub> = 480V		-	1515	-	nC		
Note: 5: The max	imum value is specified by design at T <sub>J</sub> = 150	)°C. Product is no	t tested to this condition	in produc	tion.				

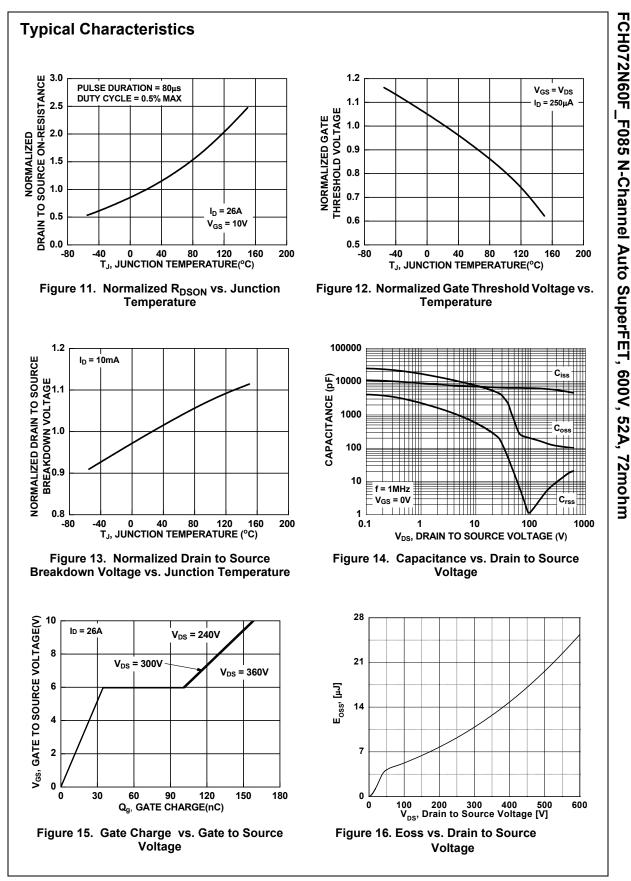
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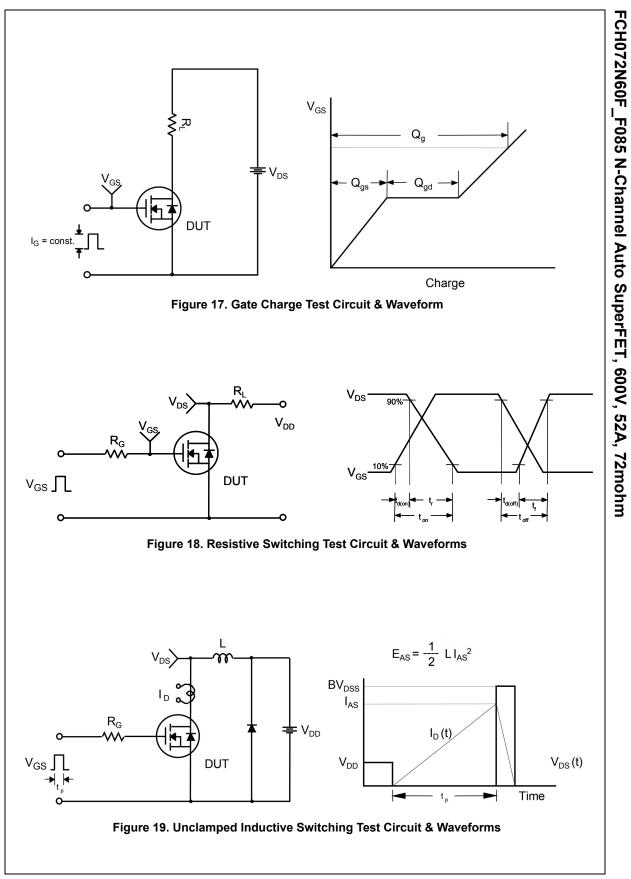
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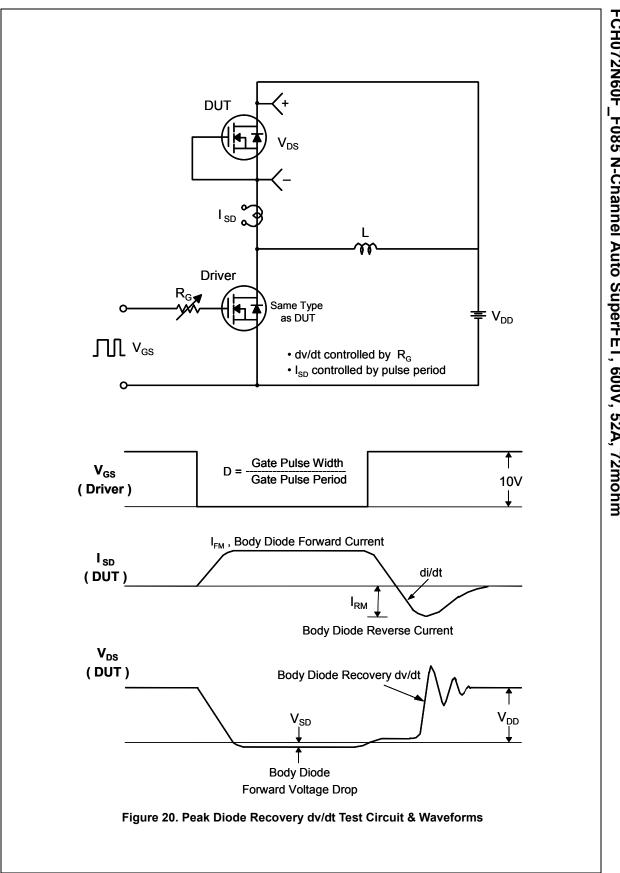
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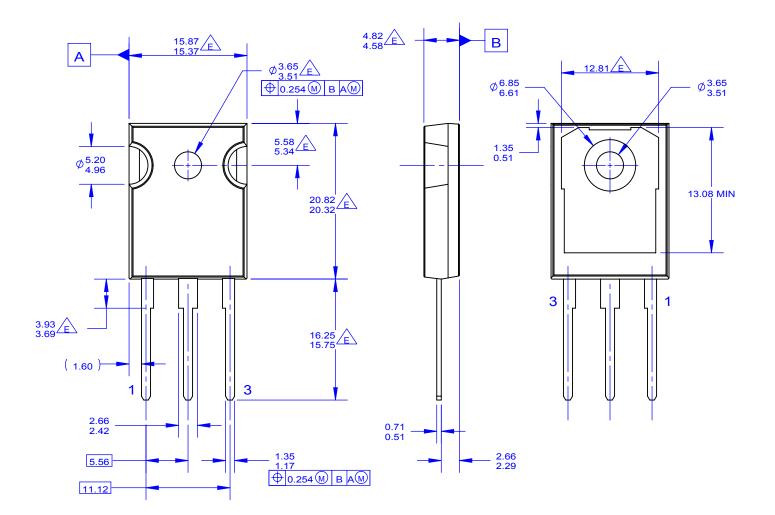


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